MMBD4148/CA/CC/SE

KEY PARAMETERS

Taiwan Semiconductor

VALUE

200

UNIT

mΑ

V

А

V

°C

SOT-23

HALOGEN

FREE

200mA, SMD Switching Diode

FEATURES

- Designed for mounting on small surface
- Low Capacitance

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EMICONDUCTOR

- Low forward voltage drop
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

V _{RRM}	100
I _{FSM}	2
V _F at I _F =10mA	1
T _J Max.	150
Package	S

PARAMETER

 I_{F}

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

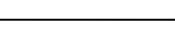
MECHANICAL DATA

- Case: SOT-23
- Molding compound meets UL 94 V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Weight: 8 mg (approximately)

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER			SYMBOL	VALUE	UNIT
	MMBD4148			5D	
Marking code on the device	MMBD4148CA			A1	
	MMBD4148CC			A4	
	MMBD4148SE			A7	
Repetitive peak reverse voltage		V _{RRM}	100	V	
Forward current			I _F	200	mA
Repetitive peak forward surge current			I _{FRM}	700	mA
Non-repetitive peak forward surge current at t=1µs at t=1s			2	- A	
		at t=1s	IFSM	1	A
Junction temperature range		TJ	-55 to +150	°C	
Storage temperature range		T _{STG}	-55 to +150	°C	



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THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-ambient thermal resistance	R _{eja}	357	°C/W	

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS SYMBO		MIN	MAX	UNIT
Forward voltage per diode (1)	I _F = 10mA, T _J = 25°C	V _F	-	1.0	V
Reverse current @ rated V_R per diode $^{(2)}$	V _R = 20V ,T _J = 25°C		-	25.0	nA
	V _R = 75V ,T _J = 25°C	I _R	-	5.0	μA
	V _R = 20V ,T _A = 150°C		-	50.0	
Reverse breakdown voltage	I _R = 5μΑ ,T _J = 25°C	N	75	-	V
	I _R = 100μΑ ,T _J = 25°C	V _(BR)	100	-	
Junction capacitance	1 MHz, V _R =0V	CJ	-	4.0	pF
Reverse recovery time	I _F =10mA,I _R =1mA, R _L =100Ω, V _R =6V	t _{rr}	-	4.0	ns

Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms

ORDERING INFORMATION			
ORDERING CODE (Note 1)	PACKAGE	PACKING	
MMBD414xx RFG	SOT-23	3K / 7" Reel	
MMBD414xx R5G	SOT-23	10K / 13" Reel	

Note:

1. "xx" defines part no. from "8" to "8SE"



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

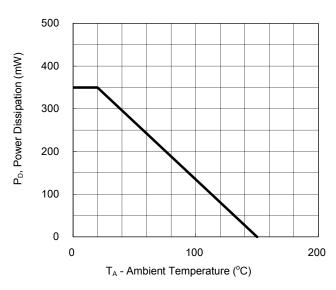


Fig. 1 Power Derating Curve

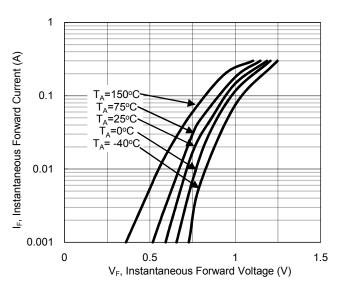


Fig.2 Forward Characteristics

Fig.3 Typical Reverse Characteristics

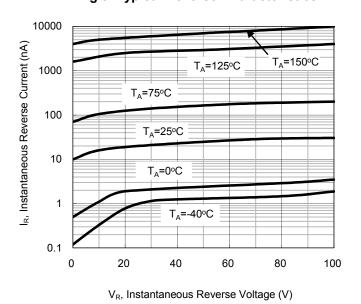
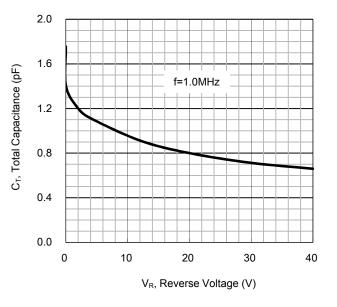


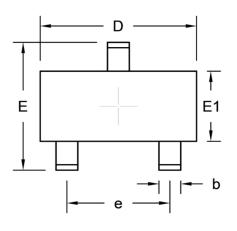
Fig.4 Typical Capacitance vs. Reverse Voltage



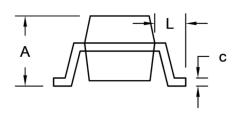
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PACKAGE OUTLINE DIMENSION

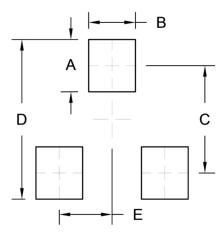
SOT-23



DIM.	Unit (mm) Min. Max.		Unit (inch)	
			Min.	Max.
A	0.89	1.30	0.035	0.051
b	0.30	0.51	0.012	0.020
с	0.10 REF.		0.004 REF.	
D	2.70	3.10	0.106	0.122
E	2.10	2.64	0.083	0.104
E1	1.10	1.50	0.043	0.059
е	1.78	2.04	0.070	0.080
L	0.55 REF.		0.022	2 REF.

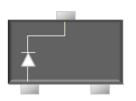


SUGGEST PAD LAYOUT

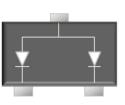


Symbol	Unit (mm)	Unit (inch)
A	0.95	0.037
В	0.85	0.033
С	1.95	0.077
D	2.90	0.114
E	0.96	0.038

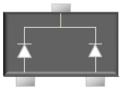
PIN CONFIGURATION



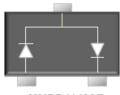
MMBD4148



MMBD4148CA



MMBD4148CC





MMBD4148/CA/CC/SE

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